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5/21/03  
Mullish

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. .... 10/087,416 /  
Filing Date ..... February 27, 2002 /  
Inventor ..... Jigish D. Trivedi et al.  
Assignee ..... Micron Technology, Inc.  
Group Art Unit ..... 2811  
Examiner ..... Douglas W. Owens  
Attorney's Docket No. ..... MI22-1965  
Title: MOS Transistors With Nitrogen in the Gate Oxide of the P-Channel Transistor



**RESPONSE TO JANUARY 17, 2003 OFFICE ACTION**

To: Mail Stop Fee Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

From: D. Brent Kenady  
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MAY 20 2003  
TECHNOLOGY CENTER 2800

Responsive to the Office Action dated January 17, 2003, Applicant amends and remarks as follows:

**AMENDMENTS**

Underlines indicate insertions and ~~strikeouts~~ indicate deletions.